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Defect Stabilized Gold Atoms on Graphene as Potential Catalysts for Ethylene Epoxidation: A First-principles Investigation

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ABSTRACT

We performed a first-principles based investigation on the potential role of Au atoms stabilized by defects on graphene in ethylene epoxidation. We showed that the interactions between the Au atoms and vacancies on graphene not only turn the Au atomic diffusion a 2.10 eV endothermic process, but also tune the energy level of Au-d states for the activation of O\textsubscript{2} and ethylene and promote the formation and dissociation of the peroxametallacycle intermediate. The catalytic cycle of ethylene epoxidation is initiated with the formation of a peroxametallacycle intermediate by the coadsorbed ethylene and O\textsubscript{2}, through the dissociation of which an ethylene epoxide molecule and an adsorbed O atom are formed. Then, gaseous ethylene reacts with the remnant O atom directly for formation of another ethylene epoxide molecule. The desorption of ethylene epoxide is facilitated by subsequent adsorption of O\textsubscript{2} or ethylene and a new reaction cycle initiates. The calculated energy barriers for the formation and dissociation of peroxametallacycle intermediate and regeneration of Au sites are 0.30, 0.84 and 0.18 eV, respectively and are significantly lower than those for aldehyde formation. These findings suggest the potential high catalytic performance of these Au atoms for ethylene epoxidation.

KEYWORDS: Graphene; monovacancy; defects; Au; ethylene; oxidation;
1. INTRODUCTION

Ethylene oxide (EO) is an important commodity chemical.\(^1\) It is used not only for production of ethylene glycol and surface-active agents such as nonionic alkylphenol ethoxylates and detergent alcohol ethoxylates, but also as the raw materials for several dozen important fine petroleum and chemical intermediates. Currently, EO is produced through vapor phase ethylene epoxidation over Ag supported on \(\alpha\)-Al\(_2\)O\(_3\) with alkali metal additives and Cl as promoters and the EO selectivity can reach 90%, while the EO selectively over pure Ag is only 40–50%.\(^2\)-\(^3\) The global market for EO is expected to exceed 27 million tons by the year 2017.\(^4\) Due to the huge global capacity of this process, even slight improvements in the selectivity would result in significant economical benefits.

In epoxidation of ethylene, the selectivity to EO is controlled by a reaction network of competing elementary pathways where a surface oxametallacycle (–OCH\(_2\)CH\(_2\)–, OMC) intermediate undergoes isomerization reactions. The selective OMC ring closure produces the EO, whereas nonselective hydride transfer within the -CH\(_2\)CH\(_2\)- leads to formation of acetaldehyde which undergoes facile nonselective combustion to CO\(_2\) and H\(_2\)O due to the high reactivity of the aldehydic C-H bond as well as the three equivalent \(\alpha\)-H next to the aldehyde group.\(^2\)-\(^3\), \(^5\)-\(^8\) The selectivity to EO is found sensitive to the exposed transition metal (TM) facets,\(^8\)-\(^9\) the size of the TM nanoparticles (NPs),\(^10\) the detailed coordination at the reaction sites, the composition of the reaction mixture\(^11\) and etc.\(^6\) Many approaches have been developed to achieve higher selectivity to EO, including morphology and size control of the TM NPs, alloying with different TMs and the utilization of novel promoters.\(^10\)-\(^17\) Au is also a Group IB metal but has long been considered to be catalytic inert due to its nobleness in bulk form. Torres et al studied the epoxidation mechanism of ethylene on an oxygen-atom-covered Au(111) surface.
theoretically.\textsuperscript{18} They showed that the predicted selectivity of ethylene epoxidation on Au(111) is \(\sim 40\%\) and is similar to that on Ag(111).\textsuperscript{2} Au NPs have attracted considerable interest due to their distinctly different catalytic properties as compared with the bulk.\textsuperscript{19-20} Au NPs supported on reducible metal-oxides showed high activity for oxidation of CO\textsuperscript{21} and alkene\textsuperscript{22-23} at low temperature and the activity can be modulated with reductive component in the mixture and even water.\textsuperscript{11, 24} Freestanding Au NPs and Au NPs supported on inert materials are also efficient and robust for selective oxidation of styrene.\textsuperscript{11, 20, 25-27} These make supported Au NPs alternative catalysts for ethylene epoxidation.

For deposited TM NPs for heterogeneous catalysis, downsizing the TM NPs size and keeping them finely dispersed is highly desired to maintain a higher density of reaction sites for better conversion and so as the catalytic performance.\textsuperscript{28} Due to the localized nature of TM-d states, their sensitivity to the local coordination and domination on the reactivity of TM NPs, the exposed unsaturated TM atoms are the reaction centers and the catalytic performance depends more strongly on the morphology than the size of TM NPs.\textsuperscript{29-31} As the size of NPs goes down, the TM-support interaction may not only alter the spacial and energetic distribution of TM states that are essential for adsorption and activation of the adsorbates,\textsuperscript{32-33} but also strongly impact the free energy of the assembly of TM atoms that sets the atomic stacking, the morphology and the durability of the TM NPs.\textsuperscript{27, 34-36} Following this, several single-atom catalysts, such as Au/FeO\textsubscript{x},\textsuperscript{37-38} Au/ZrO\textsubscript{2},\textsuperscript{39} Pd/CeO\textsubscript{2},\textsuperscript{40} Ir/Fe(OH)\textsubscript{x},\textsuperscript{41} Ag/MnO\textsubscript{x},\textsuperscript{42} Fe/SiCO\textsubscript{x}\textsuperscript{43} and etc, have been fabricated and proved efficient in reactions, including CO oxidation, hydrogenation of butadiene, methanol reforming, NO reduction, conversion of methane and etc. A thorough understanding of the TM-support interactions would be vital for the design of supported sub-nano TM NPs or even single TM atoms as catalysts for a specific reaction.
Many studies showed that defects of the supports could serve as anchoring sites for TM atoms. The defects, including dopants, vacancies and etc in graphene have been proposed to modulate the electronic structures and so as the catalytic performance of supported TM NPs and atoms.\(^{32,44-46}\) Recently, heteroatom-embedded graphene was fabricated,\(^{47}\) while Au, Cu, Fe and Pt atoms embedded in graphene have been proposed to be efficient for CO and olefin oxidation.\(^{11,48-51}\) These investigations provide strong evidence that fabrication of mono-dispersed single TM atom catalyst by defect engineering of the support materials is feasible and the resulting catalyst may display unusual behaviors compared with conventional catalysts.

Inspired by these works, we performed a first-principles-based investigation on potential role of Au atoms dispersed on graphene in ethylene epoxidation. We showed the defects on graphene interact with Au atoms strongly and turn the atomic diffusion processes highly endothermic. This strong interfacial interaction also tunes the Au-d states for the adsorption and activation of O\(_2\) and ethylene. The epoxidation of ethylene involves the formation and dissociation of a peroxametallacycle intermediate (-O-O-CH\(_2\)-CH\(_2\)-) through which an ethylene epoxide molecule and an adsorbed O atom are formed. Subsequent reactions take place between gaseous ethylene and the remnant O atom and re-initiate the catalytic cycle. The calculated energy barriers for the formation and dissociation of the peroxametallacycle intermediate and regeneration of Au site are 0.30, 0.84 and 0.18 eV, respectively and are significantly lower than those for aldehyde formation, suggesting the potential high catalytic performance of these mono-dispersed Au atoms for ethylene epoxidation. The rest of the paper is organized as the following: the theoretical methods and computational details are described in Section 2, the results are presented and discussed in Section 3 and concluded in Section 4.
2. THEORETICAL METHODS

First-principles based calculations were performed using GGA-PBE functional with DSPP pseudopotentials as implemented in DMol$^3$. A hexagonal $6 \times 6$ supercell of pristine graphene was used to mimic the graphene and the Au-graphene composites. The minimum distance between the graphene sheet and its mirror images is set to be larger than 20 Å to avoid the interactions among them. We used empirical potential for pre-optimization, and these preoptimized structures were fully relaxed in DMol$^3$ until the forces were below $1 \times 10^{-2}$ eV/Å. The transition states were located through the synchronous method with conjugated gradient refinements. For all calculations, the real-space global orbital cutoff radius was set to 4.6 Å and the energy convergence criterion was $2 \times 10^{-4}$ eV. A Γ centered $2 \times 2 \times 1$ k-point grid was used for geometry optimization and transition state search, while a $20 \times 20 \times 1$ k-point grid was used for electronic structure analysis. The Hirshfeld scheme was adapted to estimate the charge transfer. With the above setup, the minimum C-C distance in pristine graphene is 1.42 Å.

The binding energy ($E_b$) of an Au atom onto graphene(GN) is calculated as the energy difference between the Au-graphene composite (AuGN) and the clean GN substrate plus the freestanding Au atom, following Equation (1).

$$E_b = E_{AuGN} - (E_{Au} + E_{GN})$$ (1)

For the study concerning adsorption of ethylene, O$_2$, O, ethylene epoxide, acetaldehyde and etc., the adsorption energy ($E_{ad}$) is calculated as the energy difference between the species absorbed AuGN and the gaseous species plus the bare AuGN, following Equation (2).

$$E_{ad} = E_{adsorbate+AuGN} - (E_{AuGN} + E_{adsorbate})$$ (2)
3. RESULTS AND DISCUSSIONS

We started with the investigation on the dispersion of Au atoms onto pristine graphene (PGN) and found Au atoms bind weakly with PGN. The deposition of an Au atom on top of a C atom is at most 0.03 eV more plausible as compared with the other sites considered. In this configuration, Au atom stands 2.55 Å above a C atom and a corrugation of 0.15 Å in PGN is formed due to the Au-C interaction. The calculated $E_b$ is -0.10 eV and the charge transfer to PGN is 0.11 $|e|$. The small differences among the $E_b$s at various deposition sites (0.03 eV), the low atomic diffusion barrier (0.03 eV) and the small charge transfer (0.11 $|e|$) suggest the easiness for atomic diffusion and aggregation for formation of large NPs on PGN as a result of the large surface energy of these mono-dispersed Au atoms.\(^{36,62}\) One possible solution to this is to stabilize the Au atoms by forming mature interactions with the graphenic substrate to turn the atomic diffusion into a demanding process in conventional environment. The wide variety of atomic defects on chemically synthesized graphene samples, including clustered pentagons and heptagons, vacancies, edges and contaminations, provide an immediate solution in this category.\(^{63}\) We recently found that these localized defect structures on reduced graphene oxide can act as strong trapping sites for TM NPs and inhibit their aggregation.\(^{27,33}\) As the other defects can be considered as derivatives of single vacancy (SV) and its stability is similar to that of divacancy, it is typical for analyze the defective graphene-TM interaction.

Due to the larger size of Au atoms as compared with C atoms, when an Au atom is placed above a SV, it is 2.16 Å above the basal plane of graphene after geometry optimization. The charge on Au atom at the SV (AuSV) is enhanced to 0.35 $|e|$ as compared with that on PGN (0.10 $|e|$). The differential charge density showed that there are significant charge accumulation regions between the Au atoms and the neighboring C atoms, suggesting the formed interactions are
partially covalent (Figure 1a). The DOS of SV is characterized with sharp peaks around $E_F$ associated with the dangling bonds at SV.\textsuperscript{32, 64} After Au deposition, the peaks at the $E_F$ are shifted downwards, got occupied and broadened, and overlap with the peaks of Au-sp and Au-d states, showing the strong hybridization among them. (Figure 1c) This, together with the differential charge density, suggests that the Au atom uses its valence states to interact with the dangling bonds of the SV. The $E_b$ at SV (-2.20 eV) is thus enhanced by more than twenty folds as compared with that on PBN (-0.10 eV). The enhanced $E_b$ also makes the outward diffusion of Au atom to the top of its neighboring C atoms endothermic by 2.10 eV and is much higher than the Au atomic diffusion barrier of 0.03 eV on PGN, so the diffusion of SV stabilized Au atoms is kinetically prohibited in conventional environment. This binding, though is 1.73 eV less significant as compared with the calculated bulk cohesive energy of Au (3.83 eV),\textsuperscript{65} still kinetically facilitates AuSV as the initial anchor points for the growth of Au NPs as proved by the recent findings that Au NPs can be stabilized on defective graphene whose growth may be manipulated with concentration of Au precursors used.\textsuperscript{27, 66}

The spin density of AuSV (Figure 1b) is localized on the Au atom and is mainly contributed by the in-plane components of Au-d states and the C-sp states of C atoms around SV. This, in accordance with the DOS analysis, confirms that some of the partially occupied dangling Au-d states are localized at $E_F$ and resonance with C-sp states due to the Au-C interaction. The energy levels of localized d states of transition metals are known vital for the activation of adsorbed reactants and subsequent reactions.\textsuperscript{29} The dominant contribution of Au-d states at $E_F$ suggest that the transfer of electrons from AuSV for activation of adsorbates would be much easier as compared with bulk Au. In this sense, AuSV may exhibit higher reactivity in activation of adsorbed ethylene and O$_2$ for ethylene epoxidation.
Figure 1. Structure and contour plots of differential charge density (a), spin density (b) and DOS of AuSV (c). (C: Brown; Au: Dark yellow. The contour values in (a) and (b) are ± 0.005 a.u. The charge accumulation regions are in red while the charge depletion regions are in blue. The major spin density is in light yellow while the minor spin density is in light blue.)

We then investigated the adsorption of reaction species to deduce the thermodynamics of the reaction (Table 1 and Figure 2). For ethylene epoxidation over AuSV, the key reaction species are O$_2$, ethylene(EE), O, ethylene epoxide(EO) and acetyl aldehyde(AA). As PGN is chemically inert, O$_2$, EE, EO and AA are only physisorbed. In accordance with the upshift of Au-d states, the calculated $E_{ad}$ for EE is -1.32 eV, which is similar to the $E_{ad}$ of propene and is stronger than that over compact Au surfaces.$^{11,18}$ In this configuration, the EE lies on top of the Au atom with the C=C bond in plane with one of the Au-C bonds and this plane is vertical to the EE molecule plane. The nearest Au-C(EE) distance is 2.20 Å and the H-C-H angle is also distorted from ~120.0° in the planar structure to 115.2°, suggesting typical chemical bonds are formed between EE and Au and the hybridization of C(EE) atoms is changing from sp$^2$ to sp$^3$. The $E_{ad}$ of O$_2$ is -1.42 eV, corresponding to O$_2$ lying parallel to the GN surface immediately on top of the Au atom.
and the Au-O distances are both 2.17 Å. Both EE and O₂ interact strongly with AuSV, indicating that both of them can be readily adsorbed at moderate temperatures. As for O atom, it prefers to stand 1.85 Å on top of the Au atom with the Au-O direction vertical to the GN support and the corresponding Eₐₐ₅ is -4.72 eV. The enhancement of O Eₐₐ₅ can be understood as the result of lacking repulsive interaction among negative charge absorbed O atoms as compared with the case of O₂. Similar phenomena have been observed in coverage dependent O adsorption on surfaces of TMs and alloys. The Eₐₐ₅s of EO and AA are both enhanced moderately to -0.63 and -0.74 eV over AuSV, respectively and are in good accordance with those reported by Pulido et al. In the plausible configurations, EO and AA lie in the reverse direction of one of the Au-C bonds and coordinate with Au atom with their states associated with O and the nearest Au-O distances are 2.29 and 2.19 Å, respectively.

Table 1. The Eₐₐ₅s and the most plausible structures for reaction species adsorption on AuSV.

<table>
<thead>
<tr>
<th>Species</th>
<th>Eₐₐ₅ (eV)</th>
<th>Bonding Details</th>
<th>Bond</th>
<th>Length (Å)</th>
</tr>
</thead>
<tbody>
<tr>
<td>EE</td>
<td>-1.32</td>
<td></td>
<td>C1-C2</td>
<td>1.42</td>
</tr>
<tr>
<td></td>
<td></td>
<td></td>
<td>Au-C1</td>
<td>2.20</td>
</tr>
<tr>
<td></td>
<td></td>
<td></td>
<td>Au-C2</td>
<td>2.22</td>
</tr>
<tr>
<td>O₂</td>
<td>-1.42</td>
<td></td>
<td>O1-O2</td>
<td>1.35</td>
</tr>
<tr>
<td></td>
<td></td>
<td></td>
<td>Au-O1</td>
<td>2.17</td>
</tr>
<tr>
<td></td>
<td></td>
<td></td>
<td>Au-O2</td>
<td>2.17</td>
</tr>
<tr>
<td>O</td>
<td>-4.72</td>
<td></td>
<td>Au-O</td>
<td>1.85</td>
</tr>
<tr>
<td>EO</td>
<td>-0.63</td>
<td></td>
<td>Au-O</td>
<td>2.29</td>
</tr>
<tr>
<td>AA</td>
<td>-0.74</td>
<td></td>
<td>Au-O</td>
<td>2.19</td>
</tr>
</tbody>
</table>

ₐ. The Eₐₐ₅ is calculated as the energy difference between the species adsorbed on AuSV and the gaseous species plus the bare AuSV according to equation 2.

ₗ. Due to the unpaired electron on Au, the ground state of AuSV is doublet. The adsorption of O₂ and O in quartet was also considered, but was found less plausible as compared with those in doublet.
Figure 2. The most plausible adsorption structures with contour plots of differential charge density (left panel), and the corresponding DOS curves (right panel) for $O_2$, EE, O, EO and AA adsorption on AuSV. (C of EE: Blue; C of GN: Brown; Au: Dark yellow; O: Red; H: Pink. The contour value of the charge density is ± 0.005 a.u. The charge accumulation regions are in light yellow while the charge depletion regions are in light blue. The DOS curves of adsorbates are in red, those of Au-sp and Au-d are in blue and grey, respectively. The DOS curves are aligned by the calculated Fermi level.)

Due to the formation of Au-O and Au-C bonds, all the states of the adsorbates are downshifted and the shape and distribution of DOS peaks corresponding to frontier states of EE, $O_2$, EO and AA change significantly. (Figure 2c) Even some of the low lying empty states of adsorbates are split into parts and partially downshifted to below the $E_F$ to resonance strongly with the Au-d and
Au-sp states, showing the charge transfer among them. In all the cases, the charge depletion regions reside inside the adsorbates and on AuSV while the charge accumulation regions lie between AuSV and the adsorbates (Figure 2, insets in left panel), showing the direction of the charge transfer, the partial covalent nature of the bonding and the activation of the adsorbates. The calculated amounts of charge transfer among O\(_2\), EE, O, EO, AA and AuSV are 0.28, 0.04, 0.37, 0.15 and 0.12 |e|, respectively. These, together with the elongation of O-O(O\(_2\)), C-C(EE), C-O(EO), C-O(AA) distances from 1.23, 1.34, 1.44 and 1.22 Å, respectively in free molecules to 1.35, 1.42, 1.47 and 1.25 Å, respectively after adsorption further confirm the activations of adsorbates. The weak binding, small charge transfer and slight elongation of C-O bonds in EO and AA also suggest that the desorption of EO and AA might be facile, especially when coadsorbed with O\(_2\) or EE.

It has been reported that preactivation of O\(_2\) to O atom is required for EE epoxidation over Ag surfaces or NPs for formation of the OMC intermediate.\(^{67,69}\) Due to the limited coordination sites, the calculated E\(_{\text{ad}}\) for 2 O atomic adsorption is 1.48 eV less stable as compared with the adsorption of O\(_2\), implying that the direct activation of O\(_2\) to O atom is hard to take place over AuSV.\(^{11}\) As the O\(_2\) is partially activated upon adsorption, we firstly considered the direct reaction of adsorbed O\(_2\) with gaseous EE. Due to the charge transfer between O\(_2\) and AuSV, the O\(_2\)-2\(\pi\) states of antibonding character get occupied, become the frontier states and interact with the \(\pi\) antibonding states of EE for formation of a glycol like (-O-CH\(_2\)-CH\(_2\)-O-) intermediate. Though this is a 3.19 eV exothermic process, the required charge transfer from adsorbed O\(_2\) for reaction with EE makes the barrier at least 1.75 eV, while that for scission one of the O-C bonds for formation of EO and 1 adsorbed O atom is calculated as 3.07 eV. In this sense, EE would react with adsorbed O\(_2\) through other mechanisms.
In fact, the coadsorption of EE and O$_2$ is plausible over AuSV and satisfies the requirements for initiation of EE epoxidation. Previously, a similar mechanism has been proposed for the high performance of Au and Pt atoms embedded in graphene and h-BN and on Au clusters deposited over MgO and TiO$_2$ in CO oxidation.$^{48,51,70-71}$ The most plausible adsorption structure of EE and O$_2$, together with the atomic structures at various states along the minimum-energy path (MEP) are shown in Figure 3, with the corresponding structural parameters listed in Table 2.

Figure 3. Top views and side views of local configurations of the adsorbates on the AuSV at various states along the MEP for EE epoxidation, including the initial state (EP-IS1), transition states (EP-TS1, EP-TS2 and EP-TS3), intermediate state (EP-MS1) and the final states (EP-FS1 and EP-AA). (C of GN: Brown; C of EE: Blue; H: Pink; O: Red; Au: Yellow.)
Table 2. Structural Parameters of Various States along the MEP for EE Epoxidation over AuSV.

<table>
<thead>
<tr>
<th>States</th>
<th>d_{O1-O2} (Å)</th>
<th>d_{C1-C2} (Å)</th>
<th>d_{Au-O1} (Å)</th>
<th>d_{Au-O2} (Å)</th>
<th>d_{Au-C1} (Å)</th>
<th>d_{Au-C2} (Å)</th>
<th>( \angle_{H1-C2-H2} ) (°)</th>
<th>( \angle_{H2-C2-O2} ) (°)</th>
</tr>
</thead>
<tbody>
<tr>
<td>EP-IS1</td>
<td>1.30</td>
<td>1.38</td>
<td>2.23</td>
<td>3.06</td>
<td>2.39</td>
<td>2.32</td>
<td>2.99</td>
<td>117.85</td>
</tr>
<tr>
<td>EP-TS1</td>
<td>1.32</td>
<td>1.35</td>
<td>2.14</td>
<td>2.63</td>
<td>2.81</td>
<td>3.04</td>
<td>3.08</td>
<td>116.21</td>
</tr>
<tr>
<td>EP-MS1</td>
<td>1.45</td>
<td>1.52</td>
<td>2.05</td>
<td>2.94</td>
<td>2.15</td>
<td>2.89</td>
<td>1.43</td>
<td>108.82</td>
</tr>
<tr>
<td>EP-TS2</td>
<td>2.53</td>
<td>1.53</td>
<td>1.95</td>
<td>3.21</td>
<td>2.18</td>
<td>3.06</td>
<td>1.35</td>
<td>106.11</td>
</tr>
<tr>
<td>EP-FS1</td>
<td>3.13</td>
<td>1.47</td>
<td>1.86</td>
<td>2.90</td>
<td>3.66</td>
<td>3.65</td>
<td>1.45</td>
<td>117.86</td>
</tr>
<tr>
<td>EP-TS3</td>
<td>3.00</td>
<td>1.48</td>
<td>1.94</td>
<td>3.93</td>
<td>2.48</td>
<td>3.27</td>
<td>1.27</td>
<td>104.86</td>
</tr>
<tr>
<td>EP-AA</td>
<td>3.02</td>
<td>1.49</td>
<td>1.88</td>
<td>2.66</td>
<td>4.77</td>
<td>3.29</td>
<td>1.23</td>
<td>147.36</td>
</tr>
</tbody>
</table>

\( ^a \) The distance between specific atoms. Please see Figure 3 and the context for the nomination of atoms.

Though both EE and O\(_2\) gain electrons from AuSV in the coadsorbed configuration (EP-IS1), C\(_2\) atom of EE and O\(_2\) atom of O\(_2\) are of different spins and the major spin is localized on O\(_2\). This drives the O\(_2\) of O\(_2\) to move toward C\(_2\) atom of EE to reach the transition state (EP-TS1) that connects EP-IS1 to EP-MS1 on the MEP. During this endothermic process, both the structures of EE and O\(_2\) are distorted for the C\(_2\)-O\(_2\) interaction. The O1-O2 distance in O\(_2\) is stretched from 1.30 Å in EP-IS1 to 1.32 Å in EP-TS1, while the C1-C2 distance is changed from 1.38 Å after adsorption to 1.35 Å. The energy barrier for the formation of EP-MS1 is 0.30 eV and a peroxide-like OMC complex (-O1-O2-CH\(_2\)-CH\(_2\)-) is thus formed. Because the C2-O2 interaction is mature in EP-MS1, the O1-O2 distance is further elongated to 1.45 Å. The O-O distance of this length scale has been only be observed in peroxides, showing the instability of EP-MS1 and the easiness for scission of the O-O bond. The formation of EP-MS1 is exothermic by 1.18 eV as compared with EP-TS1 and the localized spin is balanced by the formation of C2-O2 bond. As a consequence of the instable peroxide structure, EP-MS1 dissociates by breaking the O1-O2 bond and forms a weakly adsorbed EO and an O atom adsorbed on AuSV (EP-FS1).

Due to the instability of both C-O bonds in EO and adsorbed O atom and the repulsive
interaction between negatively charged O2 and C1 of EE, the barrier for the formation of weakly adsorbed EO (EP-FS1) from EP-MS1 is 0.84 eV. The tendency to strengthen the C2-O2 interaction and weaken the O1-O2 and Au-C2 interaction is already apparent at the transition state (EP-TS2), where the O1-O2 distance is already as long as 2.53 Å, the Au-C2 distance has reached 3.06 Å, while the C2-O2 distance is shortened from 1.43 Å to 1.35 Å. This suggests that the dissociation of EP-MS1 is a relatively facile process and is ready to take place at moderate condition. As the $E_{ad}$ of EO is only -0.30 eV in existence of coadsorbed O atom, the desorption of EO in EP-FS1 can be considered facile.

The direct attaching of O2 to AuSV for formation of coadsorbed OMC (-O-CH$_2$-CH$_2$-) and O atom was found endothermic by 1.04 eV with respect to EP-MS1, so the reactions on this path were then ruled out. We also considered the possibility for AA formation by hydride transfer from EP-MS1. It should be noticed that the H1-Au and H2-Au distances are 3.17 and 3.91 Å in EP-MS1. As the C2-Au distance is already 2.89 Å and the 5-member ring structure of EP-MS1 is highly rigid, it is hard to consider there are direct interactions between AuSV and C2(EE) that will assist the hydride transfer of H1 from C2 to C1 for the formation of AA. Resulting from this, the path to EP-TS3 would be endothermic by 1.42 eV, though the formation of final product (EP-AA) is 2.77 eV exothermic. This high reaction barrier makes the formation of EP-AA from EP-MS1 a kinetically prohibited process and the limited coordination sites on AuSV due to the mono-dispersion of Au atoms may play a role.

The subsequent reaction takes place between a gaseous EE molecule and the adsorbed O atom over AuBV for the regeneration of Au atom as available reaction site (Figure 4 and Table 3). The O atom would be highly reactive due to the charge and spin accumulation and has been proposed as the key reaction intermediate in EE epoxidation on Ag and Au surfaces, especially
during the formation of OMC. A configuration of the EE molecule stands more than 3.0 Å away from the adsorbed atomic O on AuSV was selected as the initial state (EP-IS2). Due to the partially ionic nature of the O-Au bond, one of C(EE) get polarized and positively charged while another C(EE) get negatively charged when EE is approaching the reaction site (EP-TS4). The electrostatic C(EE)-O and C(EE)-Au interaction make the formation of OMC (EP-MS2) exothermic by 1.33 eV and the barrier is 0.54 eV. This is similar to the barrier reported for OMC formation over oxygenated surface of Au and Au NPs (0.49 and 0.23 eV, respectively). 25 The slight difference in barrier height can be attributed to the fact that both O and EE gains charge from AuSV. However, due to the enhanced Au-O and Au-C interactions in EP-MS2, the barriers for formation of EP-FS2 and EP-FS3 by scission of Au-C and hydride transfer through EP-TS5 and EP-TS6 are already 1.45 and 2.17 eV, respectively. Similar barriers for breaking of OMC has been reported on Au NPs while the significant difference in reaction barrier also suggests the potential high selectivity to EO over AuSV. 25 These high barriers also imply that breaking of EP-MS2 will slow down the subsequent reactions unless there are alternative reaction paths.

Table 3. Structural Parameters for Various States along the MEP for reaction of the gaseous EE with adsorbed O atom over AuSV. a

<table>
<thead>
<tr>
<th>States</th>
<th>( d_{C1-C2} ) (Å)</th>
<th>( d_{O1-C1} ) (Å)</th>
<th>( d_{O1-C2} ) (Å)</th>
<th>( d_{Au-O1} ) (Å)</th>
<th>( \angle_{H1-C1-H2} ) (°)</th>
<th>( \angle_{H2-C1-O1} ) (°)</th>
</tr>
</thead>
<tbody>
<tr>
<td>EP-IS2</td>
<td>1.34</td>
<td>3.40</td>
<td>3.52</td>
<td>1.85</td>
<td>116.4</td>
<td>95.1</td>
</tr>
<tr>
<td>EP-TS4</td>
<td>1.36</td>
<td>2.41</td>
<td>3.19</td>
<td>1.93</td>
<td>116.6</td>
<td>85.3</td>
</tr>
<tr>
<td>EP-MS2</td>
<td>1.52</td>
<td>1.45</td>
<td>2.34</td>
<td>2.04</td>
<td>107.9</td>
<td>108.7</td>
</tr>
<tr>
<td>EP-TS5</td>
<td>1.48</td>
<td>1.45</td>
<td>2.38</td>
<td>2.02</td>
<td>108.0</td>
<td>105.8</td>
</tr>
<tr>
<td>EP-FS2</td>
<td>1.47</td>
<td>1.47</td>
<td>2.29</td>
<td>116.7</td>
<td>114.4</td>
<td></td>
</tr>
<tr>
<td>EP-TS6</td>
<td>1.45</td>
<td>1.31</td>
<td>2.42</td>
<td>2.21</td>
<td>100.7</td>
<td>117.2</td>
</tr>
<tr>
<td>EP-FS3</td>
<td>1.48</td>
<td>1.25</td>
<td>2.39</td>
<td>2.19</td>
<td>146.8</td>
<td>119.6</td>
</tr>
<tr>
<td>EP-TS7</td>
<td>1.48</td>
<td>1.44</td>
<td>2.42</td>
<td>2.05</td>
<td>106.6</td>
<td>104.9</td>
</tr>
</tbody>
</table>

a The distance between specific atoms. Please see Figure 4 and the context for the nomination of atoms.

It has been reported that the oxidation of EE can also take place by reaction of adsorbed O atom and gaseous EE for direct formation of EO and this is also the mechanism for EE oxidation over TM complexes and oxygenated Ag2O(001) surface.72-74 The configuration that EO adsorbed on AuSV (EP-FS2) was set as the final state. Due to the charge accumulation on the remnant O atom, when the gaseous EE approaches to AuSV, the C atom of EE gets partially positively charged and interacts electrostatically with the remnant O atom to reach EP-TS7. Within EP-TS7, the C1-O1 distance is decreased from 3.40 Å in EP-IS2 to 1.44 Å and the Au-C1 distance is also decreased from 5.20 to 3.08 Å, showing that EE is pushed to the AuSV in this endothermic
process due to the interaction between C1(EE) and O1 atom. Because of the high reactivity of the adsorbed O atom and the strong exothermicity for formation of C-O bonds, the reaction barrier for formation of EP-FS2 is as low as 0.18 eV and the reaction is exothermic by 0.57 eV with respect to EP-TS7. We also investigated the AA formation (EP-FS3) from the unactivated EE as a process competing with that of EO, but the calculated barrier is as high as 3.05 eV. In this sense, the formation of AA from EP-IS2 would also be a kinetically forbidden process and EO will be the dominant product. This is similar to EO formation over oxygenated Ag₂O (001) where the surface oxide structure limits the binding of ethylene with Ag cations for AA formation. Following the EO formation, O₂ and EE adsorption will take place for formation of coadsorption structures or even compete with the adsorption of EO. We investigated the coadsorption of EO with O₂ and EE and found that E_ad of EO is decreased to -0.18 and -0.30 eV, respectively, which implies the desorption of EO and the proceeding of the reaction facile.

Figure 5. Schematic energy profile corresponding to local configurations shown in Figures 3, and Figure 4 along the MEP for EE epoxidation over AuSV. All energies are given with respect to the reference energy, i.e., the sum of energies of the clean AuSV and gaseous EE and O₂ molecules.
In summary, the EE epoxidation over AuSV may be characterized as the following: The EE catalytic epoxidation cycle is initiated with reaction of the coadsorbed EE and O\textsubscript{2} (EP-IS1) to form a peroxide like complex (EP-MS1), by the dissociation of which the an EO molecule and an adsorbed O atom are formed (EP-FS1), and then the AuSV is regenerated to be available by the reaction of a gaseous EE with the adsorbed O atom (EP-IS2) to form another EO (EP-FS2). (Figure 5) We investigated the evolution of DOS of EE and O\textsubscript{2} during the reaction (Figure S1) and realized that the potential high catalytic performance of AuSV can be attributed to the compatibility of the states of AuSV and adsorbed intermediates, particularly among the upshifted Au-d states originated from the interfacial Au-C interactions and the molecular states of EE and O\textsubscript{2}, that facilitates the required charge transfer for the reaction to proceed. The limited binding sites resulting from the mono-dispersion of the Au atoms differentiates the reaction barriers for formation of EO and AA and accounts for the potentially high selectivity to EO.\textsuperscript{74}

4. CONCLUSION

We performed a first-principles-based investigation on the potential catalytic role of Au atoms dispersed on graphene in ethylene epoxidation. We showed the Au atom binds strongly onto the vacancy on graphene and the outward diffusing of the Au atom is endothermic by 2.10 eV, which make the diffusion and aggregation of these monodispersed Au atoms a kinetically prohibited process in conventional conditions. This strong interfacial interaction also tunes the energy level of Au-d states for the activation of O\textsubscript{2} and EE and promotes the formation and dissociation of the peroxametallacycle intermediate. The ethylene epoxidation over AuSV involves the formation of a peroxametallacycle intermediate by the coadsorbed EE and O\textsubscript{2}, the dissociation of the peroxametallacycle intermediate for formation of an EO molecule and an adsorbed O atom, the direct reaction of another gaseous EE with the remnant O atom for the
formation of EO and the coadsorption of EE or O₂ that facilitates the EO desorption and acts as the initiation of another reaction cycle. The calculated barriers for the formation and dissociation of oxametallacycle intermediate and regeneration of Au site are 0.30, 0.84 and 0.18 eV, respectively and are significantly lower than those for aldehyde formation, indicating the potential high catalytic performance of these mono-dispersed Au atoms for ethylene epoxidation. These findings also highlight the possibility to regulate the selectivity of structure sensitive reactions by limiting the coordination and interaction of the TM centers with the reaction intermediates and would be helpful for future design and implementation of high performance single-atom catalysts.

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Author Contributions

X. L. designed the research after discussion with Y.H. and C. M. and wrote the manuscript. Y. Y. conceived the calculations and analyzed the results with the assistance of M. C. and T. D. Y. Y. is responsible for the calculation results. Y. H. and C. M. proofed the manuscript and polished the language. All authors have given approval to the final version of the manuscript.

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Defect Stabilized Gold Atoms on Graphene as Potential Catalysts for Ethylene Epoxidation: A First-principles Investigation

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The defects on graphene make Au atoms active while monodispersed and superior for ethylene epoxidation.

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